## Features

- $50 \Omega$ Impedance
- Input Terminated
- Positive Voltage Control
- High Isolation: 50 dB at 2500 MHz
- 0.5 micron GaAs pHEMT Process
- Lead-Free 3 mm 16-Lead PQFN Package
- 100\% Matte Tin Plating over Copper
- RoHS* Compliant


## Applications

- Multi Market / MMIC
- Metro Long Haul


## Description

The MASW-011207 is a GaAs pHEMT MMIC single pole double throw (SPDT) switch in a lead-free 3 mm 16-lead PQFN package. The MASW-011207 is ideally suited for applications where low control voltage, high isolation, small size and low cost are required. This part can be used in all $50 \Omega$ systems operating up to 3 GHz .

The MASW-011207 is fabricated using a 0.5 micron gate length GaAs pHEMT process. The process features full passivation for performance and reliability.

## Ordering Information ${ }^{1,2}$

| Part Number | Package |
| :---: | :---: |
| MASW-011207-TR1000 | 1000 piece reel |
| MASW-011207-TR3000 | 3000 piece reel |
| MASW-011207-001SMB | Sample Board |

1. Reference Application Note M513 for reel size information.
2. All sample boards include 5 loose parts.

## Functional Schematic



## Pin Configuration ${ }^{3}$

| Pin \# | Pin Name | Description |
| :---: | :---: | :---: |
| $1,2,4,5,6,9$, <br> $12,15,16$ | N/C | No Connection |
| 3 | RFC | RF Common Port |
| 7 | RF2 | RF Port 2 |
| 8 | GT2 | RF Ground |
| 10 | V2 | Vcontrol 2 |
| 11 | V1 | Vcontrol 1 |
| 13 | GT1 | RF Ground |
| 14 | RF1 | RF Port 1 |

3. The exposed pad centered on the package bottom must be connected to RF and DC ground.
[^0]Electrical Specifications: $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{Z}_{0}=50 \Omega^{4}, \mathrm{~V}_{\mathrm{C}}=0 \mathrm{~V} / 2.9 \mathrm{~V}, \mathrm{P}_{\mathrm{IN}}=5 \mathrm{dBm}$

| Parameter | Test Conditions | Units | Min. | Typ. | Max. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Insertion Loss | $\begin{aligned} & 216 \mathrm{MHz} \\ & 550 \mathrm{MHz} \\ & 810 \mathrm{MHz} \\ & 1000 \mathrm{MHz} \\ & 2200 \mathrm{MHz} \\ & 2500 \mathrm{MHz} \\ & 3000 \mathrm{MHz} \end{aligned}$ | dB | - | $\begin{aligned} & 0.64 \\ & 0.65 \\ & 0.66 \\ & 0.67 \\ & 0.73 \\ & 0.75 \\ & 0.80 \end{aligned}$ | $\begin{aligned} & - \\ & \bar{Z} \\ & 1.2 \end{aligned}$ |
| $\begin{gathered} \text { Isolation } \\ \text { RFC-RF1,RF2 } \end{gathered}$ | $\begin{aligned} & 216 \mathrm{MHz} \\ & 550 \mathrm{MHz} \\ & 810 \mathrm{MHz} \\ & 1000 \mathrm{MHz} \\ & 2200 \mathrm{MHz} \\ & 2500 \mathrm{MHz} \\ & 3000 \mathrm{MHz} \end{aligned}$ | dB | 65 $\overline{52}$ $\overline{48}$ - | $\begin{aligned} & 70 \\ & 62 \\ & 58 \\ & 56 \\ & 53 \\ & 52 \\ & 53 \end{aligned}$ | - |
| Isolation RF1-RF2 | $\begin{aligned} & 216 \mathrm{MHz} \\ & 550 \mathrm{MHz} \\ & 810 \mathrm{MHz} \\ & 1000 \mathrm{MHz} \end{aligned}$ | dB | - | $\begin{aligned} & 88 \\ & 80 \\ & 74 \\ & 70 \\ & \hline \end{aligned}$ | - |
| Return Loss (on-state) | $\begin{aligned} & 5-1000 \mathrm{MHz} \\ & 5-2500 \mathrm{MHz} \end{aligned}$ | dB | - | $\begin{aligned} & 27 \\ & 26 \end{aligned}$ | - |
| Return Loss (off-state) | $5-1000 \mathrm{MHz}$ | dB | - | $\begin{aligned} & 24 \\ & 18 \end{aligned}$ | - |
| Input P1dB | 2000 MHz | dBm | - | 24 | - |
| IIP3 | 2 tone, $5 \mathrm{dBm} /$ tone, 6 MHz spacing, $\mathrm{f} 1 \& \mathrm{f} 2=988 \& 994 \mathrm{MHz}$ | dBm | - | 51 | - |
| IIP2 | 2 tone, $5 \mathrm{dBm} /$ tone, 6 MHz spacing, $\mathrm{f} 1 \& \mathrm{f} 2=988 \& 994 \mathrm{MHz}$ | dBm | - | 91 | - |
| $\mathrm{T}_{\text {RISE, }}, \mathrm{T}_{\text {FALL }}$ | 10\% to $90 \%$ RF, $90 \%$ to $10 \%$ RF | ns | - | 16 | - |
| Ton, $\mathrm{T}_{\text {OfF }}$ | 50\% control to 90\% RF, 50\% control to 10\% RF | ns | - | 8 | - |
| Transients | In Band | mV | - | 70 | - |
| Control Current | $\left\|\mathrm{V}_{\mathrm{C}}\right\|=2.9 \mathrm{~V}$ | $\mu \mathrm{A}$ | - | 5 | 10 |

4. External $0.01 \mu$ F DC blocking capacitors are required on all RF In/Out and RF ground ports (GT1 and GT2). See Application Schematic.

## Absolute Maximum Ratings ${ }^{5,6}$

| Parameter | Absolute Maximum |
| :---: | :---: |
| Input Power | 32 dBm |
| $(5-3000 \mathrm{MHz}, 2.9 \mathrm{~V}$ Control $)$ | 8.5 V |
| Operating Voltage | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Operating Temperature | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Storage Temperature |  |

## Maximum Operating Limits

| Parameter | Maximum |
| :---: | :---: |
| RF Input Power | 24 dBm |
| $\mathrm{V}_{\text {CONTROL }}$ | 5 V |
| Operating Temperature | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

5. Exceeding any one or combination of these limits may cause permanent damage.
6. Macom does not recommend sustained operation near these survivability limits.

Truth Table ${ }^{7}$

| V1 | V2 | RFC - RF1 | RFC - RF2 |
| :---: | :---: | :---: | :---: |
| 1 | 0 | On | Off |
| 0 | 1 | Off | On |

7. $1=+2.9$ to $+5 \mathrm{~V}, 0=0 \pm 0.2 \mathrm{~V}$.

## Application Schematic



## Handling Procedures

Please observe the following precautions to avoid damage:

## Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these Class OB HBM and Class C3 CDM devices.

## Evaluation Board



## Evaluation Board Losses



## Typical Performance Curves

$\mathrm{P}_{\text {IN }}=5 \mathrm{dBm}, \mathrm{V}_{\mathrm{C}}=0 \mathrm{~V} / 2.9 \mathrm{~V}, \mathrm{Z}_{0}=50 \Omega$ (unless otherwise indicated)

Insertion Loss RFC to RF1


Isolation RFC to RF1


Isolation RF1 to RF2 (RF1 On)


Insertion Loss RFC to RF2


Isolation RFC to RF2


Isolation RF1 to RF2 (RF2 On)


## Typical Performance Curves

$\mathrm{P}_{\mathrm{IN}}=5 \mathrm{dBm}, \mathrm{V}_{\mathrm{C}}=0 \mathrm{~V} / 2.9 \mathrm{~V}, \mathrm{Z}_{0}=50 \Omega$ (unless otherwise indicated)

RF1 Return Loss On-state match (RF2 Off)


RF1 Return Loss Off-state (RF2 On)


RFC to RF1 Port Switch Compression @ 2 GHz


RF2 Return Loss On-state match (RF1 Off)


RF2 Return Loss Off-state (RF1 On)


RFC to RF2 Port Switch Compression @ 2 GHz


## Lead-Free 3 mm 16-Lead PQFN ${ }^{\dagger}$


${ }^{\dagger}$ Reference Application Note M538 for lead-free solder reflow recommendations.
Meets JEDEC moisture sensitivity level 1 requirements.

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[^0]:    * Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

